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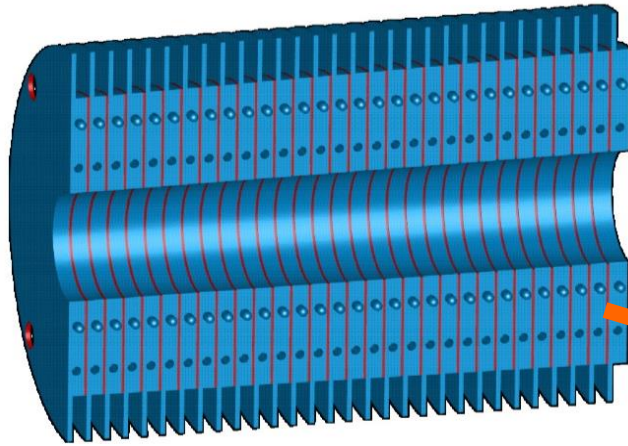
# **Investigation of the properties of diamond radiation detectors**

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E. Kouznetsova, W. Lohmann

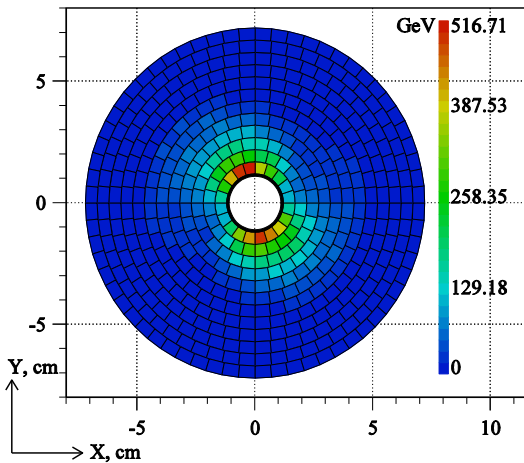
FCAL Workshop, TelAviv, 2005

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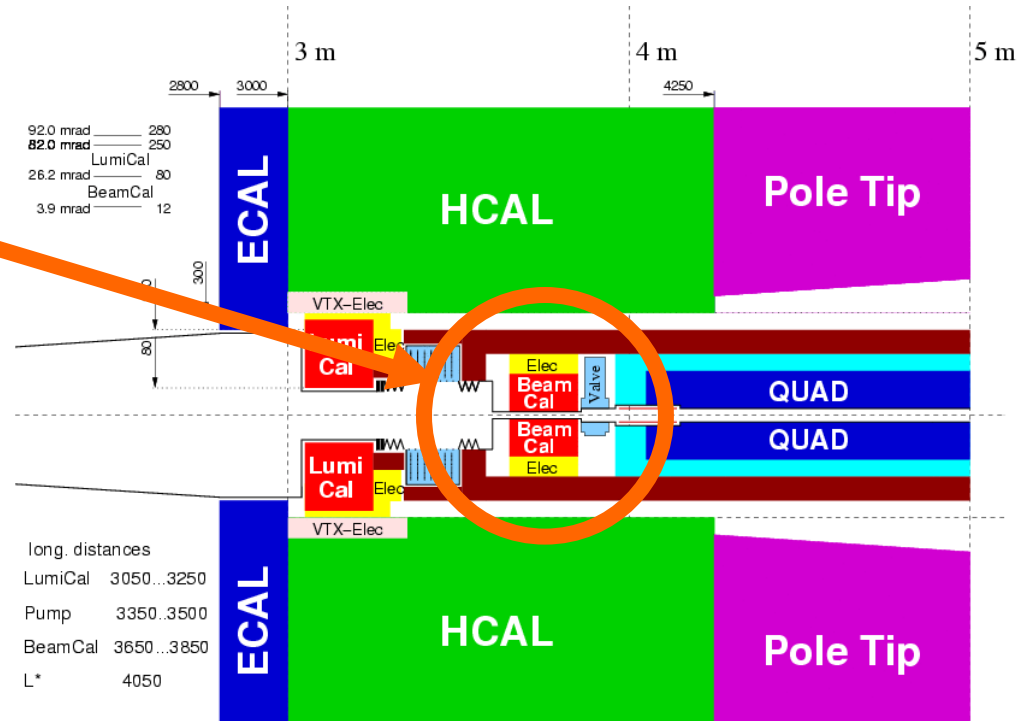
# Possible Applications



Sampling diamond-tungsten calorimeter



ILC Detector forward calorimeter



Expected dose from beamstrahlung is about 10 MGy per year

# Diamond as detector

Diamond have very high radiation hardness (doses up to 10 MGy)

This makes diamond very promising material for the next generation colliders

It also have unique properties, such as low conductivity, high thermoconductivity, wide bandgap, chemical inertness

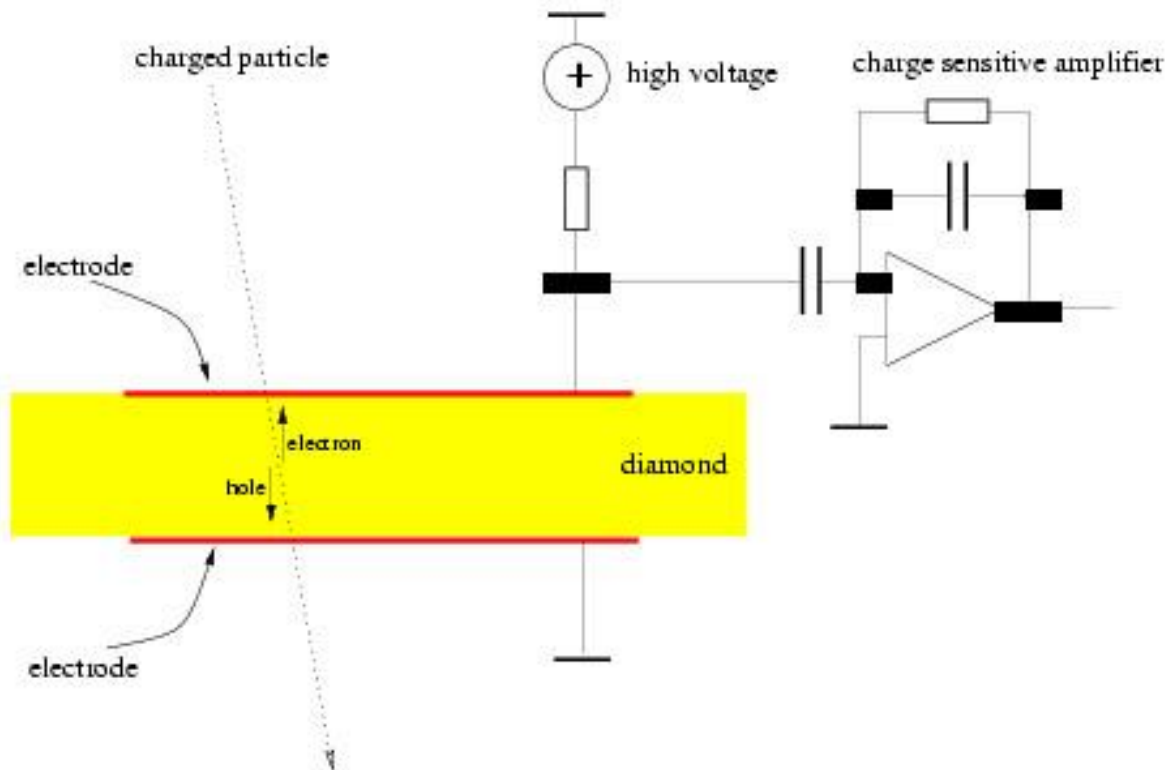
Physical properties of

	Silicon	Diamond
density, $g/cm^3$	2.33	3.5
thermal conductivity, $\frac{W}{m \times K}$	150	>1000
→ resistivity, $\Omega \times cm$	$2.3 \times 10^5$	$>10^{11}$
carrier density, $cm^{-3}$	$1.5 \times 10^{10}$	$<10^3$
dielectric constant	11.9	5.7
→ capacity (1 $cm^2$ , 500 $\mu m$ ), $pF$	35	17
leakage current, $pA/mm^2$	550	35
breakdown field, $V/cm$	$3 \times 10^5$	$10^7$
→ band gap, $eV$	1.12	5.5
energy/e-h, $eV$	3.6	13
→ electron mobility, $\frac{cm^2}{V \times s}$	1350	1800
hole mobility, $\frac{cm^2}{V \times s}$	480	1200
saturation velocity, $km/s$	82	220
corresponding field, $V/cm$	$E_d = f(L)$	$10^4$
pair number/100 $\mu m$ (mip), $e$	9200	3600
energy deposition/100 $\mu m$ (mip), $keV$	40	50
efficiency	1 ( $E > E_d$ )	$\frac{d_c}{L}$
$d_c$ , $\mu m$	-	60 - 250
radiation length, $cm$	9.4	12.0
Moliere radius, $cm$	5.28	12.31

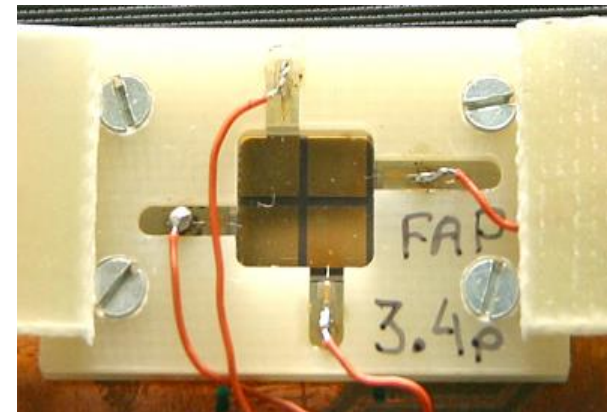
# Detection mechanism

Diamond works as a solid state ionization chamber

Charge carriers, generated by ionizing particle move in an external electric field and induce charge on the surface electrodes



This charge is detected by a charge-sensitive preamplifier



# The samples

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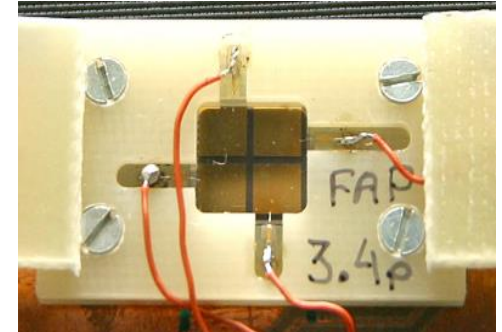
## Chemical vapor deposited (CVD) polycrystalline samples:

A large selection of samples from Fraunhofer IAF, Freiburg

12x12 mm plates with thickness 200 - 700  $\mu\text{m}$

Metallization: 10 nm Ti + 400nm Au

1 pad or 4 pad segmentation



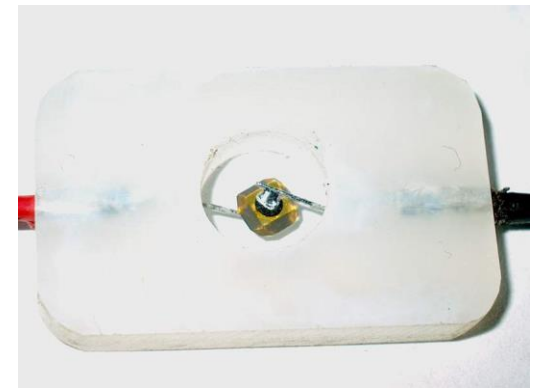
2 samples from Element Six (former De Beers Industrial Diamonds)

## HPHT synthetic monocrystalline samples:

From ADAMAS BSU

Typical size 4x4 mm, thickness 300 - 600  $\mu\text{m}$

Metallization: **Fe-Ni with B ion implantation**



## 1 sample of natural monocrystalline diamond

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# Charge collection distance

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Performance of diamond as particle detector is usually characterized by charge collection efficiency  $\varepsilon$  or distance (CCD)

Efficiency is given by  $\varepsilon = Q_{\text{meas}}/Q_{\text{ind}}$

where  $Q_{\text{meas}}$  is measured charge and  $Q_{\text{ind}}$  - total charge generated

Charge collection distance equals  $\text{CCD} = \varepsilon * d$

where  $d$  is the thickness of the sample

CCD could be considered as separation between charge carrier pair before trapping

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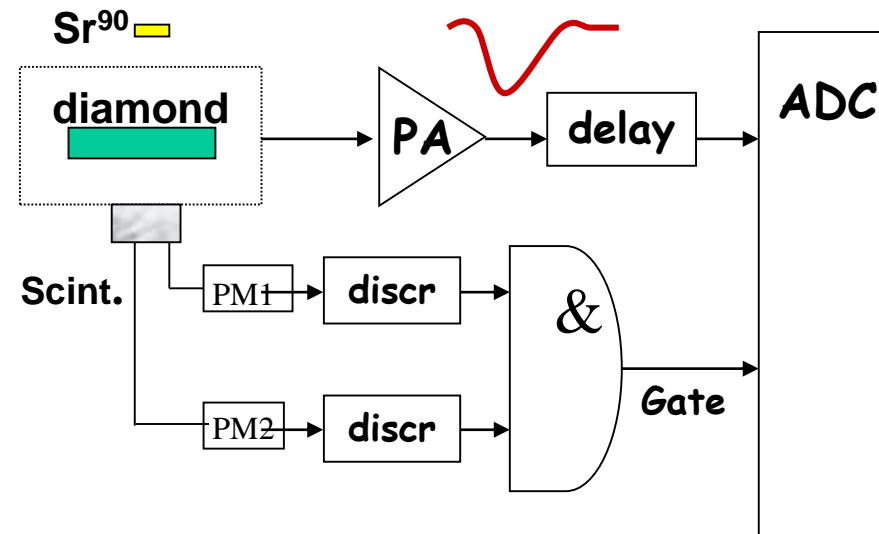
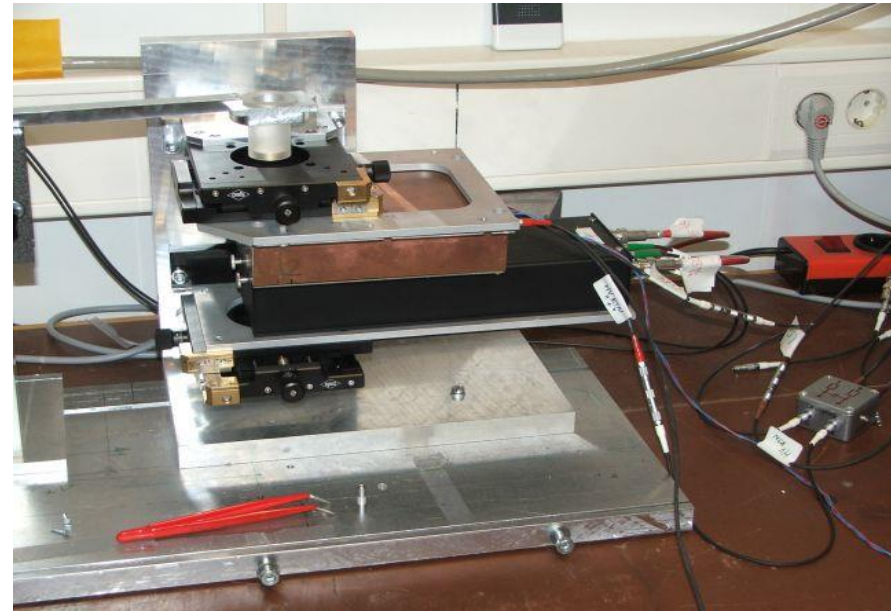
# CCD Measurement

To measure CCD we need to know the exact amount of charge carriers generated

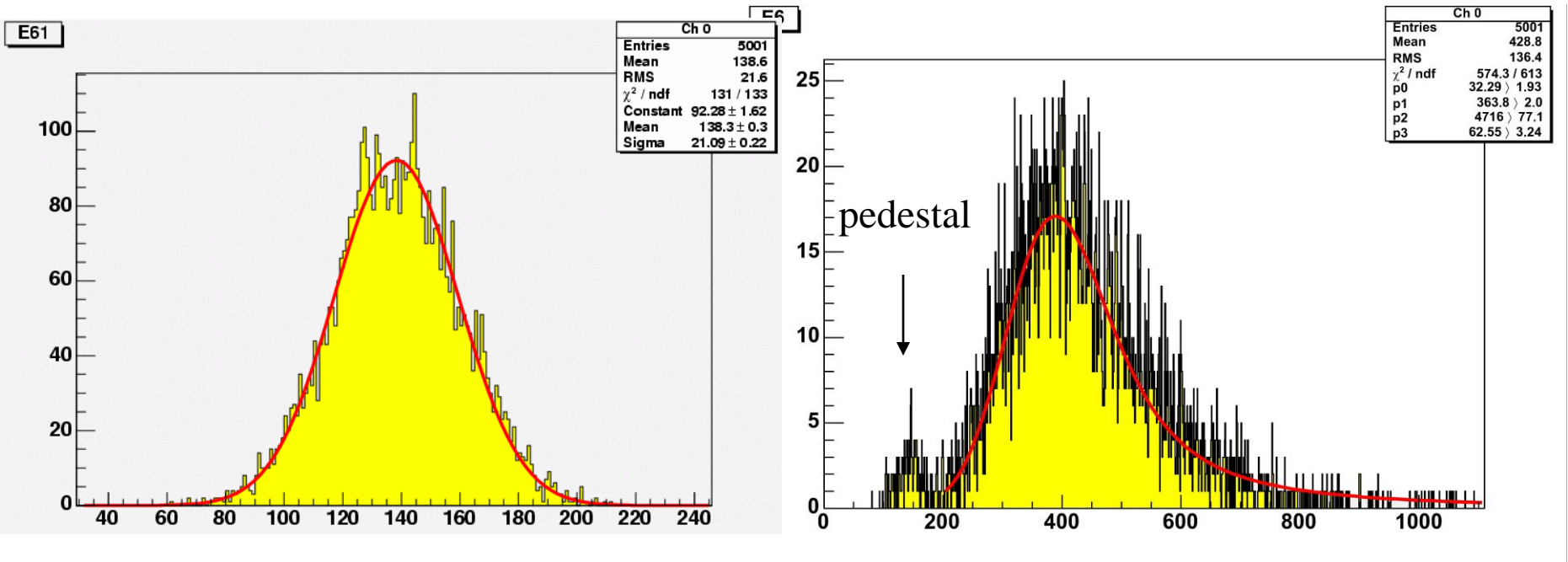
But we know that a MIP generates about 36 e<sup>-</sup>-h pairs per 1 μm pathlength in diamond

In this case  $CCD = Q_{\text{meas}} / 36$

Scintillator allows triggering only from particles which could be considered MIPS



# CCD Measurement



Pedestal (random trigger)

Signal (MIP trigger)

Signal charge value could be calculated from this pair of spectra by subtracting pedestal and multiplying by charge/ADC channel value from calibration.



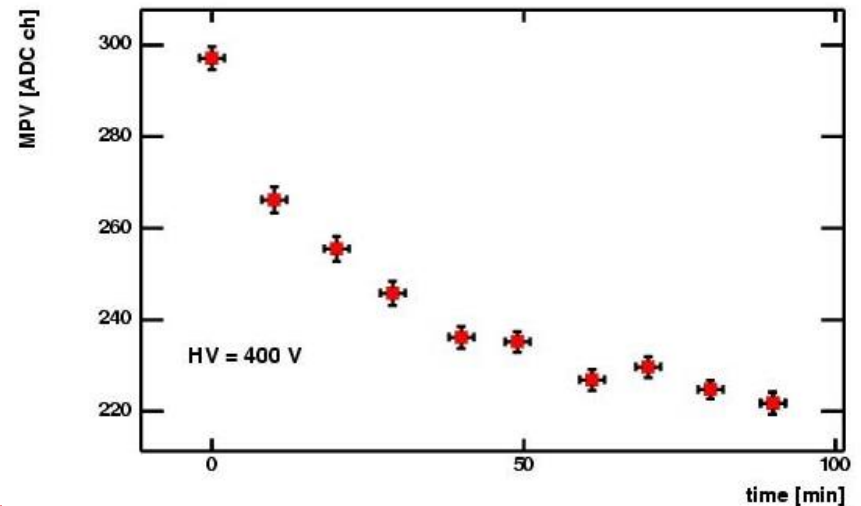
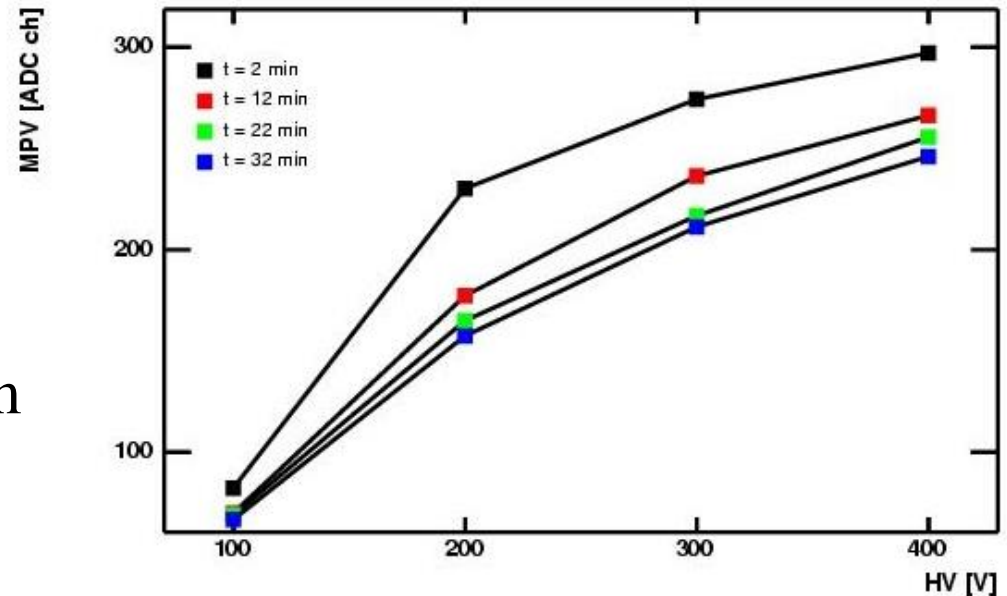
# CCD vs HV and time

Charge collection distance depends on bias voltage applied to the sample

Saturation is observed at field strength of about  $1\text{ V}/\mu\text{m}$

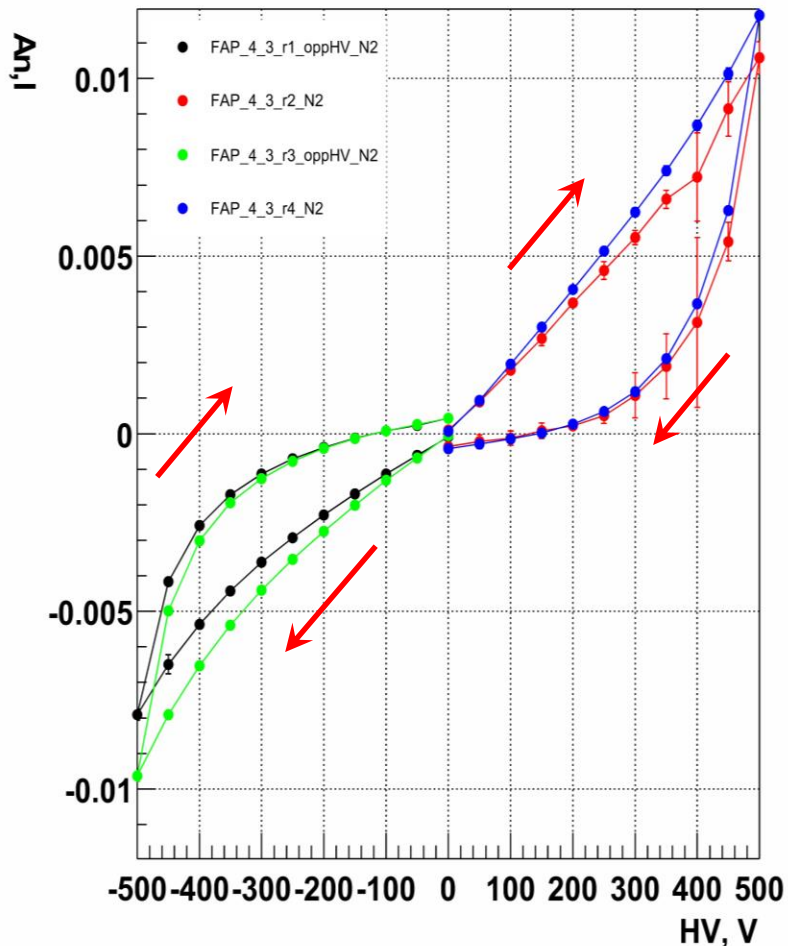
There is also dependence of CCD on time with HV on

This is probably due to some kind of space-charge effect from trapped charge carriers

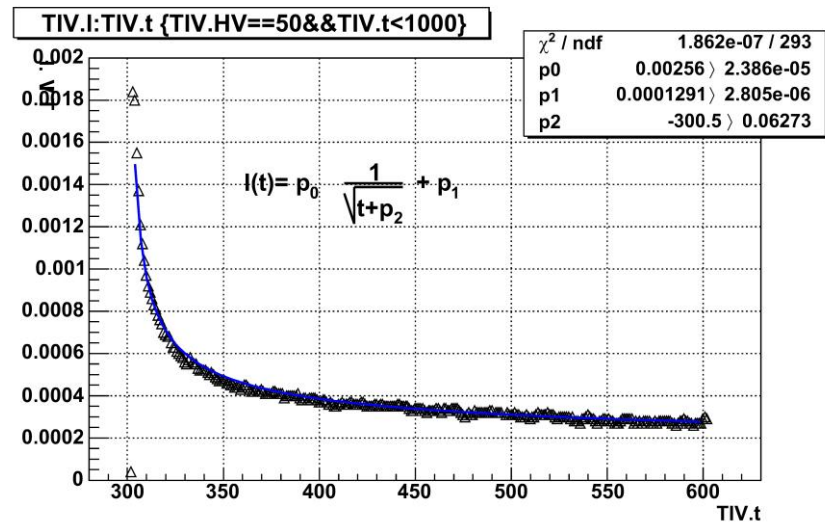


# IV Measurement

FAP4/FAP\_4\_3\_Final



Most of the samples show ohmic behavior and very high resistance in the order of  $10^{13}$ - $10^{14}$  ohm

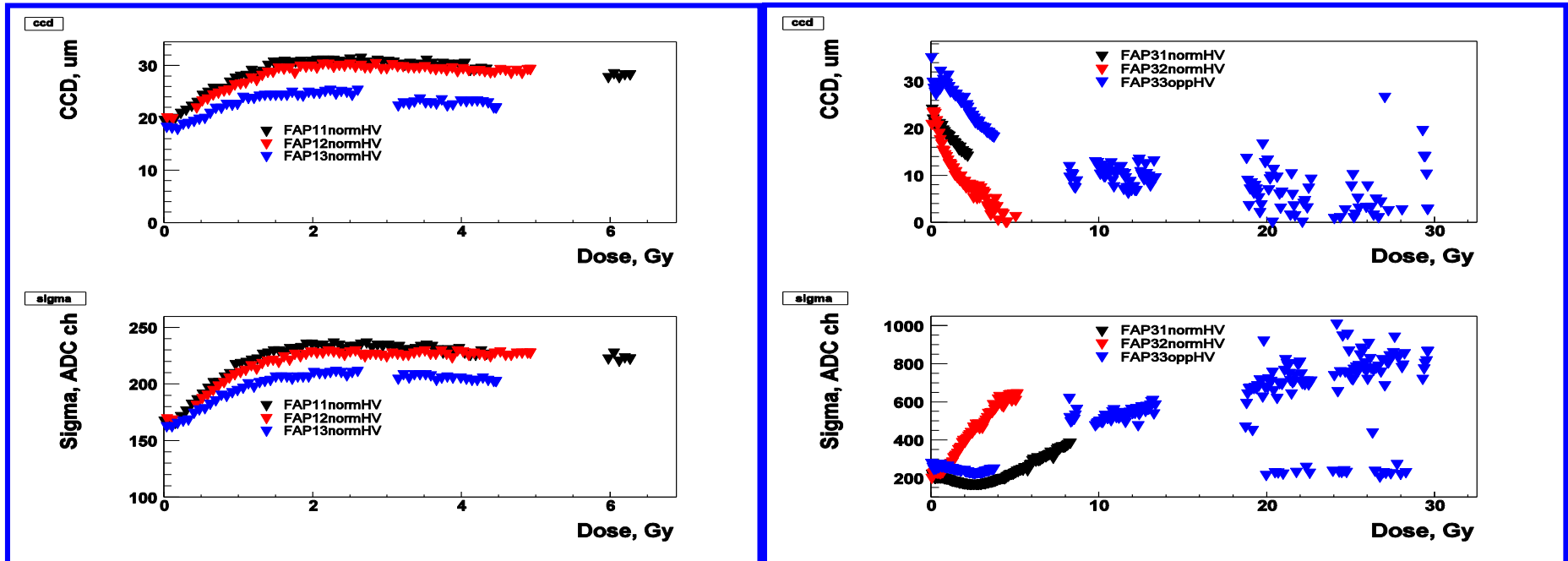


Settling time of the current is in the order of 100 s. Hysteresis is probably due to polarisation.

# CCD vs Dose

Diamond is stable under irradiation with doses up to 10 MGy

But in the process of irradiation detector properties could change



Most of the samples show similar behavior  
CDD is rising with the dose by approx. 10-20%  
and then stabilises

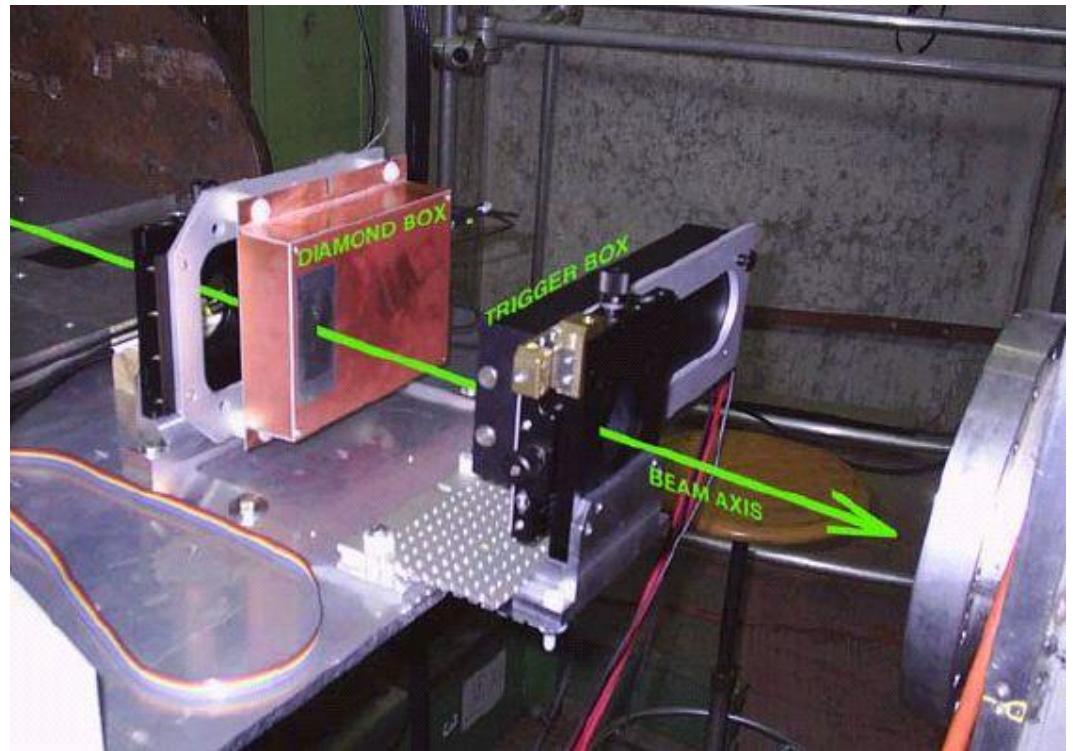
But some samples show complete  
degradation of signal and sharp rise  
of the current under irradiation

# Linearity

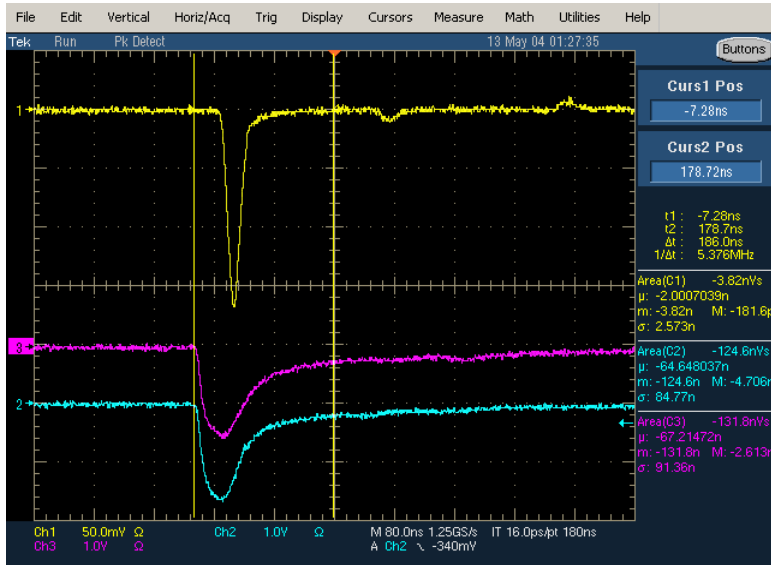
- A linear behavior over high dynamic range is required for the calorimetry application.
- We have checked this at a beamtest at CERN

Setup consists of a box with diamond and preamplifier and scintillator trigger box

Incident hadronic beam with approx. 4 GeV energy and intensity from  $10^5 - 10^6 / s$  up to  $10^5 - 10^7 / 10ns$

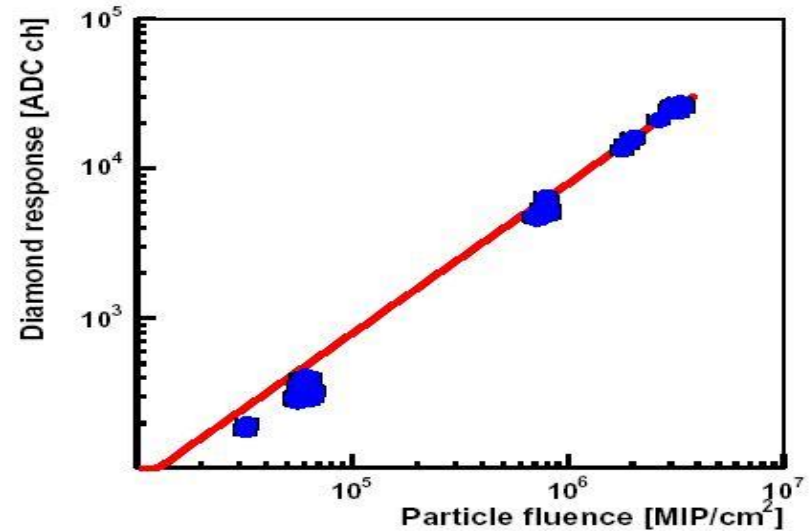
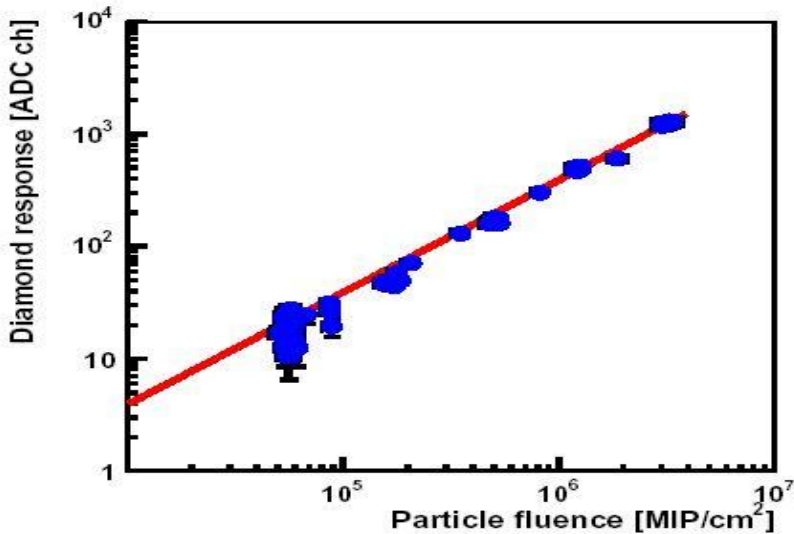


# Linearity



Signal at high intensity clearly visible w/o preamplifier

Good linearity for two samples over the dynamic range of  $10^2$



# Trapping

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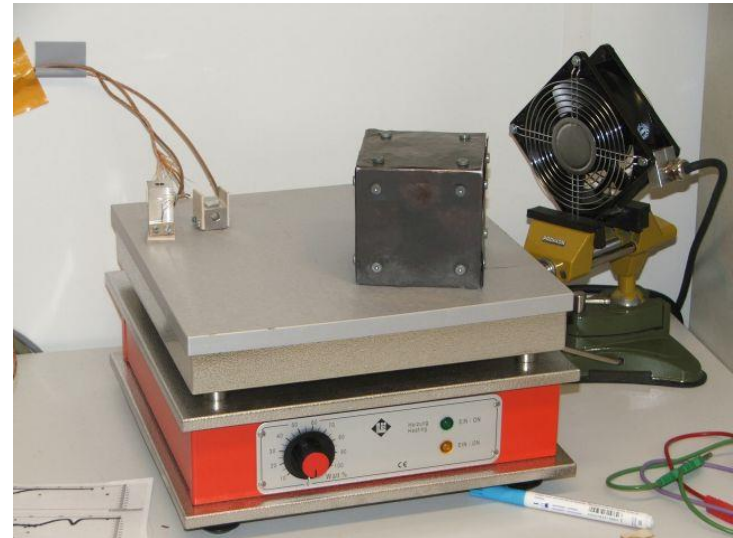
- Trapping of the charge carriers is the main cause of low CCD.
  - Traps could be impurities, defects and other irregularities of crystalline structure.
  - Filling of traps produces space charge in the crystal and could give rise to polarisation effects
  - If we have several trapping levels with different activation energy, density and cross section, the dynamics of trapping will be really weird.
  - On the other hand filling of deep traps leads to “pumping effect”
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# TSC measurements

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- TSC means thermally stimulated currents
- The idea is that if we have charge carrier trapping in the diamond at room temperature, then heating the sample up could free trapped charge carriers and produce detectable current. The current peak position vs temperature gives the idea about energy levels of traps.

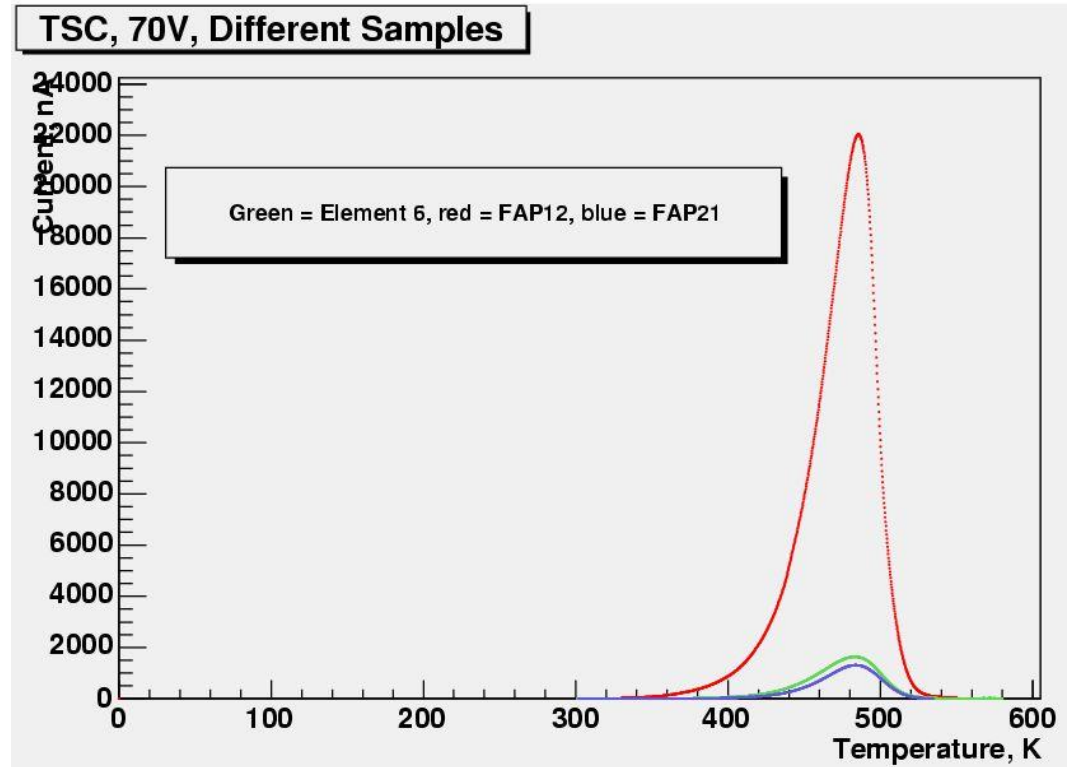
Setup consists of heating plate  
electronic thermometer with  
thermopair, HV supply and  
picoammeter



# TSC measurements

- TSC data for different diamonds

Peak position corresponds to energy of about 0,8-1 eV

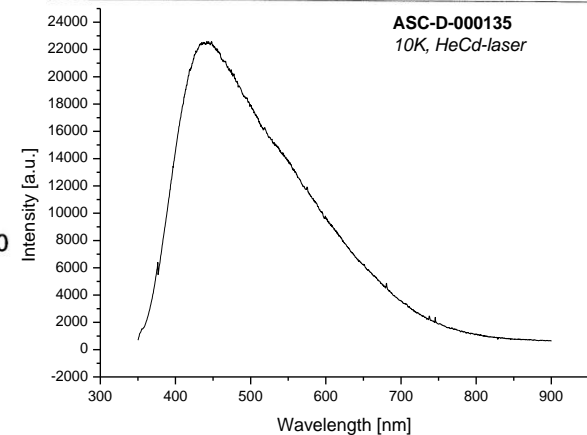
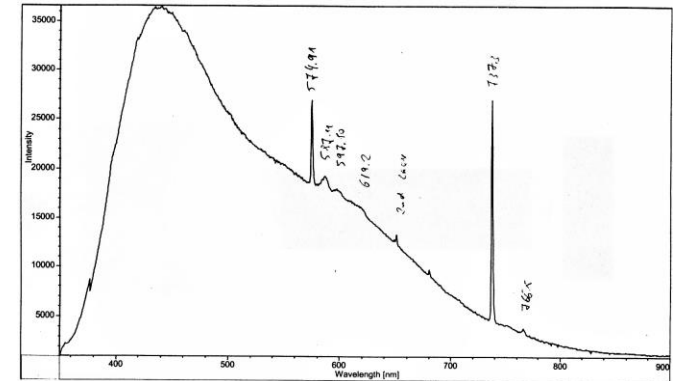
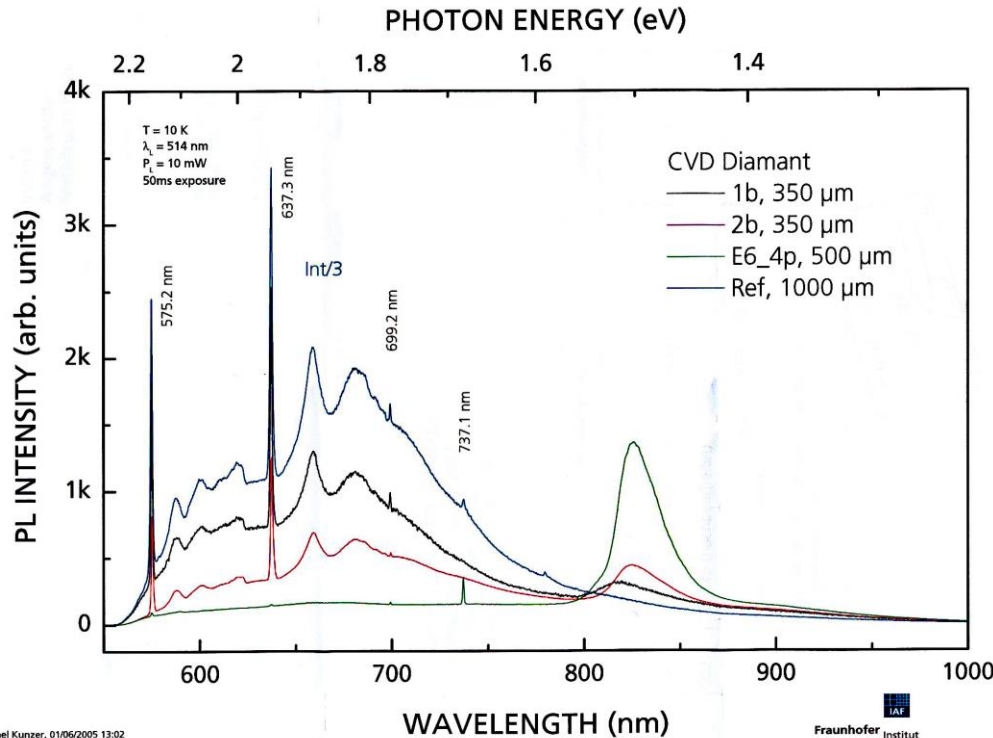


TSC “resets” sample, but the shape is similar for different samples



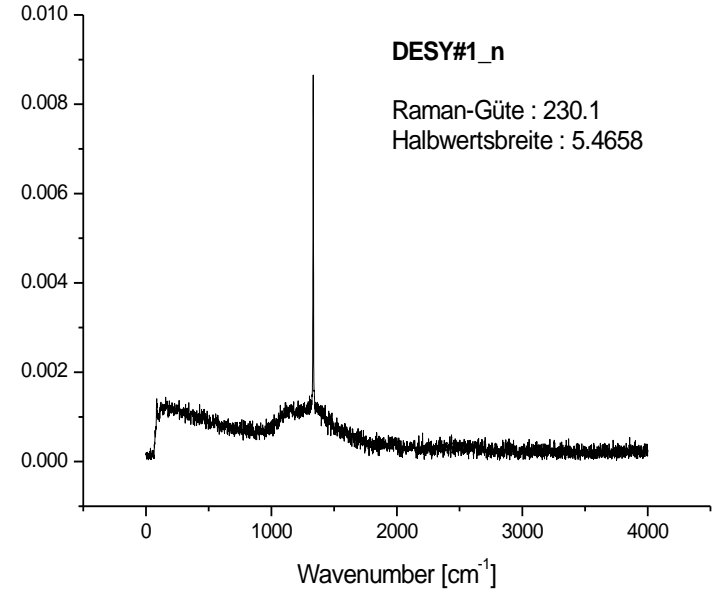
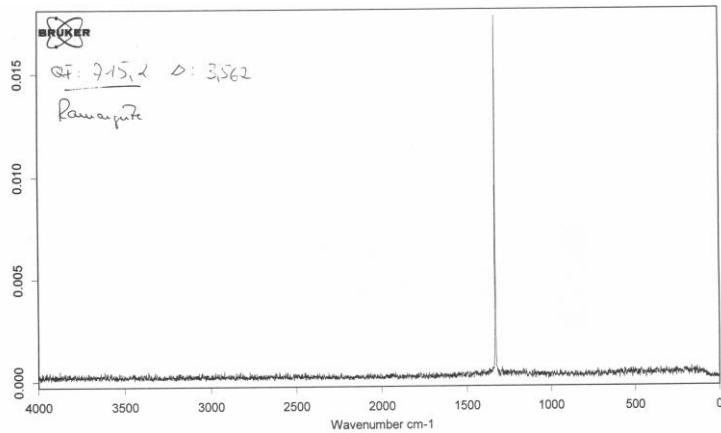
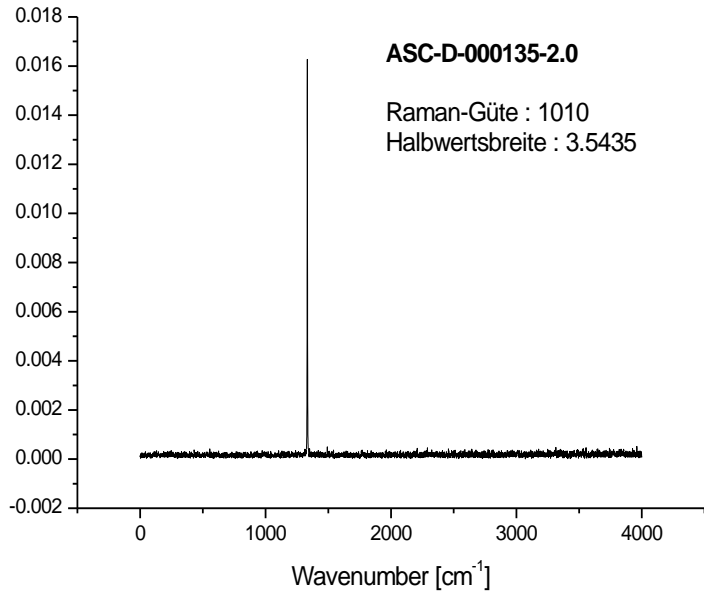
# PL Spectra

- Photoluminescence spectra of different samples



There seems to be a correlation between detector properties and PL

# Raman Spectra



# Conclusion

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Diamond sensors work and we have results both from CVD and synthetic monocrystalline diamonds.

The sensors have good radiation hardness and linear response. But the CCD vs time behavior and dependence of CCD on dose complicates use of diamond sensors in calorimetry.

In the present state diamond sensors already could be used for beam monitoring.

## Future work

- Need to establish close contact with manufacturer, find a method to characterize samples (TL, raman?) and get interpretation from the material scientists
  - Further study of the influence of metallization and surface treatment is needed
  - A study of radiation hardness with large doses is planned
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